

SOT-23 Formed SMD Package

**CMBT5088
CMBT5089**

NPN SILICON PLANAR EPITAXIAL TRANSISTORS

N-P-N transistors

**PACKAGE OUTLINE DETAILS
ALL DIMENSIONS IN mm**

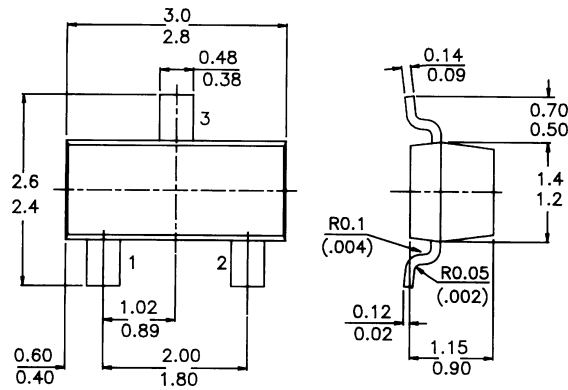
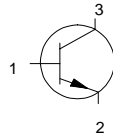
Marking

CMBT5088 = 1Q

CMBT5089 = 1R

Pin configuration

- 1 = BASE
- 2 = EMITTER
- 3 = COLLECTOR



ABSOLUTE MAXIMUM RATINGS

| | | 5088 | 5089 |
|--|-------------|----------------------|------------------|
| Collector-base voltage (open emitter) | V_{CB0} | max. 35 | 30 V |
| Collector-emitter voltage (open base) | V_{CE0} | max. 30 | 25 V |
| Collector current | I_C | max. 50 | mA |
| Total power dissipation up to $T_{amb} = 25\text{ }^\circ\text{C}$ | P_{tot}^* | max. 225 | mW |
| Junction temperature | T_j | max. 150 | $^\circ\text{C}$ |
| Collector-emitter saturation voltage $I_C = 10\text{ mA}; I_B = 1\text{ mA}$ | V_{CEsat} | max. 0.5 | V |
| D.C. current gain $I_C = 100\text{ }\mu\text{A}; V_{CE} = 5\text{ V}$ | h_{FE} | min. 300 max. 900 | 400 1200 |
| Transition frequency at $f = 20\text{ MHz}$ $I_C = 500\text{ }\mu\text{A}; V_{CE} = 5\text{ V}$ | f_T | min. 50 | MHz |

*FR-5 Board = 1.0 × 0.75 × 0.062 in.

RATINGS (at $T_A = 25^\circ\text{C}$ unless otherwise specified)*Limiting values*

| | | 5088 | 5089 |
|--|------------------|-------------|------------------|
| Collector-base voltage (open emitter) | V_{CBO} max. | 35 | 30 V |
| Collector-emitter voltage (open base) | V_{CEO} max. | 30 | 25 V |
| Emitter-base voltage (open collector) | V_{EBO} max. | 4.5 | V |
| Collector current (d.c.) | I_C max. | 50 | mA |
| Total power dissipation up to $T_{amb} = 25^\circ\text{C}$ | P_{tot}^* max. | 225 | mW |
| Storage temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |
| Junction temperature | T_j max. | 150 | $^\circ\text{C}$ |

THERMAL RESISTANCE

| | | | |
|--------------------------|---------------|-----|--------------------|
| From junction to ambient | $R_{th\ j-a}$ | 417 | $^\circ\text{C/W}$ |
|--------------------------|---------------|-----|--------------------|

CHARACTERISTICS $T_{amb} = 25^\circ\text{C}$ unless otherwise specified

| | | 5088 | 5089 |
|--|---------------|-------------|-------------|
| Collector cut-off current | | | |
| $I_E = 0; V_{CB} = 20\text{ V}$ | $I_{CBO} <$ | 50 | - nA |
| $I_E = 0; V_{CB} = 15\text{ V}$ | $I_{CBO} <$ | - | 50 nA |
| Emitter cut-off current | | | |
| $I_C = 0; V_{EB} = 3\text{ V}$ | $I_{EBO} <$ | 50 | - nA |
| $I_C = 0; V_{EB} = 4.5\text{ V}$ | $I_{EBO} <$ | - | 100 nA |
| Saturation voltages | | | |
| $I_C = 10\text{ mA}; I_B = 1\text{ mA}$ | $V_{CEsat} <$ | 500 | mV |
| | $V_{BEsat} <$ | 800 | mV |
| Collector capacitance at $f = 100\text{ KHz}$ | | | |
| Emitter guarded | | | |
| $I_E = 0; V_{CB} = 5\text{ V}$ | $C_{cb} <$ | 4.0 | pF |
| Emitter capacitance at $f = 100\text{ KHz}$ | | | |
| Emitter guarded | | | |
| $I_C = 0; V_{EB} = 0.5\text{ V}$ | $C_{eb} <$ | 10 | pF |
| D.C. current gain | | | |
| $I_C = 0.1\ \mu\text{A}; V_{CE} = 5\text{ V}$ | h_{FE} | 300-900 | 400-1200 |
| $I_C = 1.0\text{ mA}; V_{CE} = 5\text{ V}$ | $h_{FE} >$ | 350 | 450 |
| $I_C = 10\text{ mA}; V_{CE} = 5\text{ V}$ | $h_{FE} >$ | 300 | 400 |
| Small signal current gain | | | |
| $I_C = 1\text{ mA}; V_{CE} = 5\text{ V}; f = 1\text{ KHz}$ | h_{fe} | 350-1400 | 450-1800 |
| Transition frequency at $f = 20\text{ MHz}$ | | | |
| $I_C = 500\ \mu\text{A}; V_{CE} = 5\text{ V}$ | $f_T >$ | 50 | MHz |
| Noise figure at $R_S = 10\text{ k}\Omega$ | | | |
| $I_C = 100\ \mu\text{A}; V_{CE} = 5\text{ V}$ | $N_F <$ | 3.0 | 2.0 dB |
| $f = 10\text{ Hz to }15.7\text{ Hz}$ | | | |

*FR-5 Board = $1.0 \times 0.75 \times 0.62\text{ in.}$

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